# 74HC03; 74HCT03

# Quad 2-input NAND gate Rev. 3 — 27 June 2013

Product data sheet

#### 1. **General description**

The 74HC03; 74HCT03 is a quad 2-input NAND gate with open-drain outputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### **Features and benefits** 2.

- Input levels:
  - ◆ For 74HC03: CMOS level
  - ◆ For 74HCT03: TTL level
- ESD protection:
  - ♦ HBM JESD22-A114F exceeds 2000 V
  - ♦ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

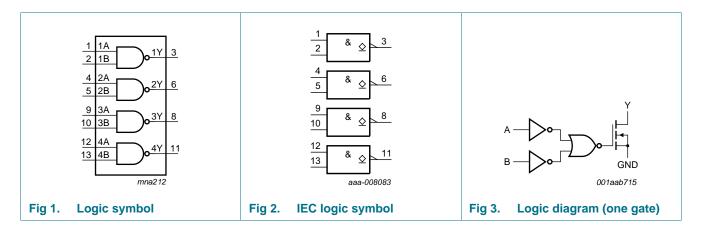
#### 3. **Ordering information**

Table 1. **Ordering information** 

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74HC03N	−40 °C to +125 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1						
74HCT03N										
74HC03D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1						
74HCT03D			3.9 mm							
74HC03DB	–40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body	SOT337-1						
74HCT03DB			width 5.3 mm							
74HC03PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1						
74HCT03PW			body width 4.4 mm							

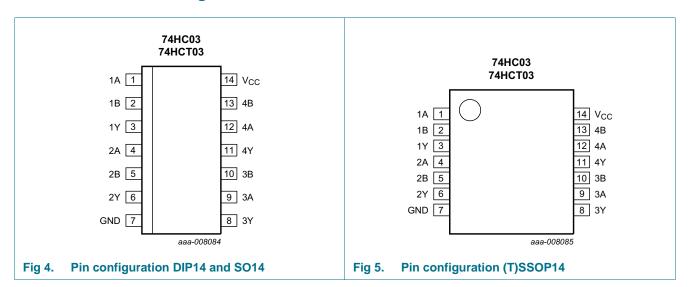


## 4. Functional diagram



## 5. Pinning information

### 5.1 Pinning



#### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A to 4A	1, 4, 9, 12	data input
1B to 4B	2, 5, 10, 13	data input
1Y to 4Y	3, 6, 8, 11	data output
GND	7	ground (0 V)
V <sub>CC</sub>	14	supply voltage

## 6. Functional description

Table 3. Function table[1]

Input	Output	
nA	nB	nY
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		, ,		. •	
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
Vo	output voltage		<u>[1]</u> –0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V}$	<u>[1]</u> -	-20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}}$	-	-25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation		[2]		
	DIP14 package		-	750	mW
	SO14 and (T)SSOP14 packages		-	500	mW
	<u> </u>				

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC03		74HCT03			Unit	
			Min	Тур	Max	Min	Тур	Max		
$V_{CC}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V	
VI	input voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V	
Vo	output voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V	
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C	

74HC\_HCT03

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<sup>[2]</sup> For DIP14 package: P<sub>tot</sub> derates linearly with 12 mW/K above 70 °C.
For SO14 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.
For (T)SSOP14 packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.

 Table 5.
 Recommended operating conditions ...continued

Voltages are referenced to GND (ground = 0 V) ...continued

Symbol	Parameter	Conditions	74HC03		74HCT03			Unit	
			Min	Тур	Max	Min	Тур	Max	
$\Delta t/\Delta V$ input transition rise and fall ra	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V

## 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC03										
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 \text{ V}$	4.2	3.2	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level	$V_{CC} = 2.0 \text{ V}$	-	8.0	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 \text{ V}$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	-	1.8	-	1.8	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}$ ; $V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	0.1	-	-	±1	-	±1	μА
I <sub>OZ</sub>	OFF-state output current	per input pin; $V_I = V_{IL}$ ; $V_O = V_{CC}$ or GND; other inputs at $V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$ ; $I_O = 0 \text{ A}$	-	-	±0.5	-	±5.0	-	±10	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	2.0	-	-	20	-	40	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT0	3									
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	0.8	-	0.8	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 4.0 \text{ mA}$	-	0.15	0.26	-	0.33	-	0.4	V

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
II	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>OZ</sub>	OFF-state output current	per input pin; $V_I = V_{IL}$ ; $V_O = V_{CC}$ or GND; other inputs at $V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$ ; $I_O = 0 \text{ A}$	-	-	±0.5	-	±5.0	-	±10	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	2.0	-	20	-	40	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $\begin{aligned} &V_I = V_{CC} - 2.1 \text{ V; } I_O = 0 \text{ A;} \\ &\text{other inputs at } V_{CC} \text{ or GND;} \\ &V_{CC} = 4.5 \text{ V to } 5.5 \text{ V} \end{aligned}$	-	100	360	-	450	-	490	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

## 10. Dynamic characteristics

#### Table 7. Dynamic characteristics

 $GND = 0 \text{ V; } C_L = 50 \text{ pF; for load circuit, see } Figure 7.$ 

Symbol	Parameter	Conditions			25 °C		-40 °C to	+125 °C	Unit
				Min	Тур	Max	Max (85 °C)	Max (125 °C)	
74HC03									
t <sub>pd</sub>	propagation delay	nA, nB to nY; see Figure 6	[1]						
		$V_{CC} = 2.0 \text{ V}$		-	28	95	120	145	ns
		V <sub>CC</sub> = 4.5 V		-	10	19	24	29	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	8	-	-	-	ns
		V <sub>CC</sub> = 6.0 V		-	8	16	20	25	ns
t <sub>t</sub>	transition time	see Figure 6	[2]						
		V <sub>CC</sub> = 2.0 V		-	19	75	95	110	ns
		V <sub>CC</sub> = 4.5 V		-	7	15	19	22	ns
		V <sub>CC</sub> = 6.0 V		-	6	13	16	19	ns
$C_{PD}$	power dissipation capacitance	per package; $V_I = GND$ to $V_{CC}$	<u>[3]</u>	-	4	-	-	-	pF

**Table 7. Dynamic characteristics** ...continued GND = 0 V;  $C_L = 50$  pF; for load circuit, see Figure 7.

Symbol	Parameter	Conditions	Conditions		25 °C			o +125 °C	Unit
			Min	Тур	Max	Max (85 °C)	Max (125 °C)		
74HCT03	3							'	
t <sub>pd</sub>	propagation delay	nA, nB to nY; see Figure 6	<u>[1]</u>						
		$V_{CC} = 4.5 \text{ V}$		-	12	24	30	36	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	10	-	-	-	ns
t <sub>t</sub>	transition time	V <sub>CC</sub> = 4.5 V; see Figure 6	[2]	-	7	15	19	22	ns
$C_{PD}$	power dissipation capacitance	per package; V <sub>I</sub> = GND to V <sub>CC</sub> – 1.5 V	<u>[3]</u>	-	4	-	-	-	pF

- [1]  $t_{pd}$  is the same as  $t_{PLZ}$  and  $t_{PZL}$ .
- [2]  $t_t$  is the same as  $t_{THL}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

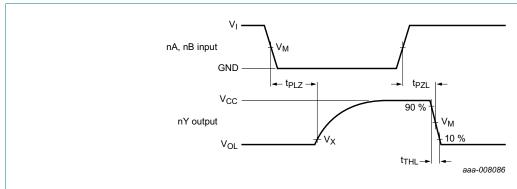
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### 11. Waveforms



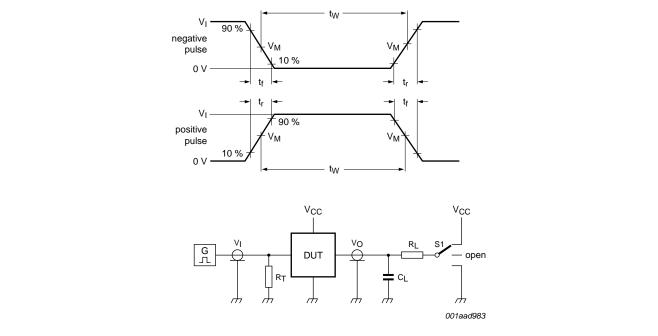
Measurement points are given in Table 8.

 $V_{\mbox{\scriptsize OL}}$  and  $V_{\mbox{\scriptsize OH}}$  are typical voltage output levels that occur with the output load.

Fig 6. Input to output propagation delays

Table 8. Measurement points

Туре	Input	Output				
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>			
74HC03	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	0.1V <sub>CC</sub>			
74HCT03	1.3 V	1.3 V	0.1V <sub>CC</sub>			



Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = load capacitance including jig and probe capacitance.

Fig 7. Test circuit for measuring switching times

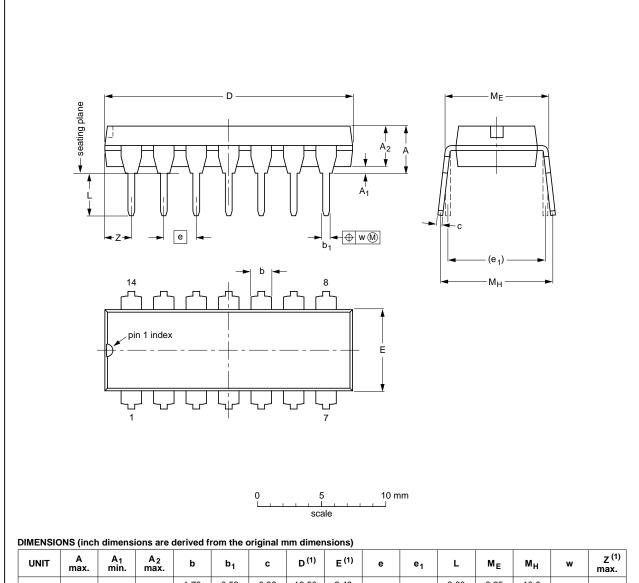
Table 9. Test data

Туре	Input L		Load	S1 position	
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74HC03	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	V <sub>CC</sub>
74HCT03	3.0 V	6 ns	15 pF, 50 pF	1 kΩ	V <sub>CC</sub>

## 12. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.02	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT27-1	050G04	MO-001	SC-501-14		<del>99-12-27</del> 03-02-13	

Fig 8. Package outline SOT27-1 (DIP14)

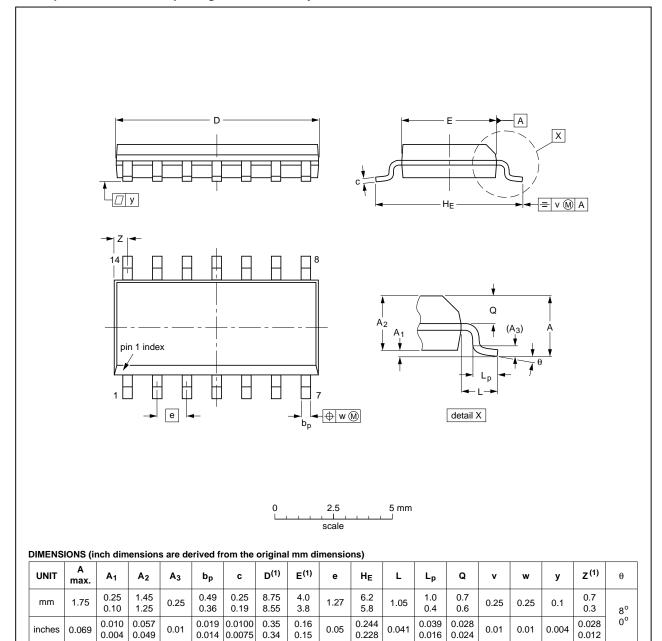
74HC\_HCT03

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

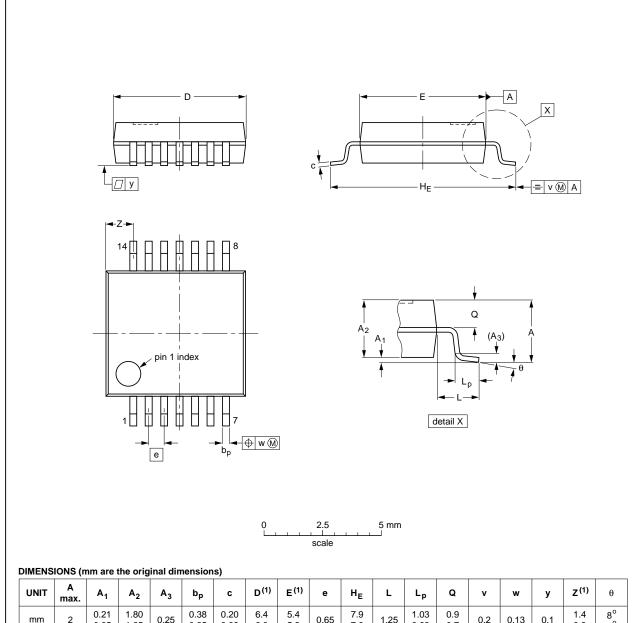
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012			<del>99-12-27</del> 03-02-19	

Fig 9. Package outline SOT108-1 (SO14)

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

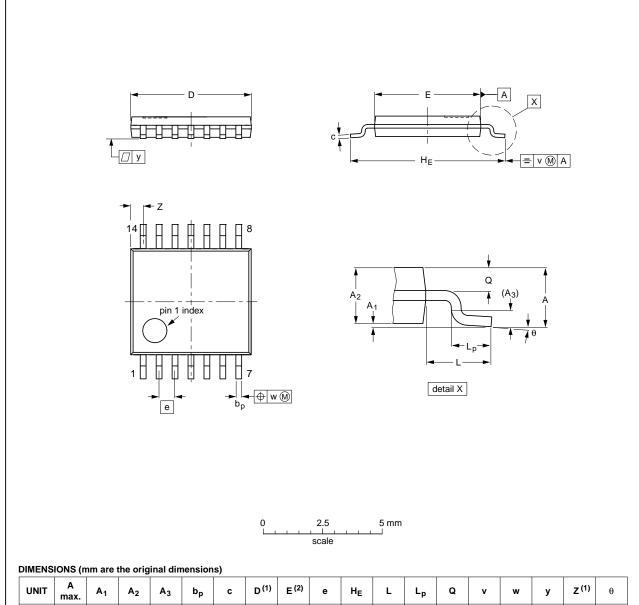
	OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE	
VERSION		IEC	JEDEC	JEITA	PROJECTION		ISSUE DATE	
	SOT337-1		MO-150				<del>99-12-27</del> 03-02-19	
_			•		•			-

Fig 10. Package outline SOT337-1 (SSOP14)

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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



UNIT	Α	A <sub>1</sub>	A2	A <sub>3</sub>	b <sub>p</sub>	С	D <sup>(1)</sup>	E (2)	e	He	L	L <sub>p</sub>	o	v	w	v	Z <sup>(1)</sup>	θ
	max.		2		р	,						_b		-		,		
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT402-1		MO-153			<del>99-12-27</del> 03-02-18	

Fig 11. Package outline SOT402-1 (TSSOP14)

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## 13. Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT03 v.3	20130627	Product data sheet	-	74HC_HCT03_CNV v.2
Modifications:	<ul> <li>The format of this d of NXP Semiconduction</li> </ul>	ata sheet has been redes ctors.	igned to comply with the	e new identity guidelines
	<ul> <li>Legal texts have be</li> </ul>	en adapted to the new co	mpany name where app	propriate.
74HC_HCT03_CNV v.2	19970827	Product specification	-	-

## 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### **Quad 2-input NAND gate**

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